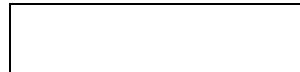


**6**

**(a)**

A student wishes to determine the *I-V* characteristics of a semiconductor diode.



**(i)**

Draw a suitable labelled diagram of the circuit that would enable the student to collect data to determine the *I-V* characteristics of the semiconductor diode.

[2]



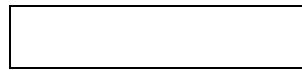
(ii)

Sketch, on Fig. 6.1, the  $I$ - $V$  characteristics of a semiconductor diode in forward bias.



Fig. 6.1

[1]



(iii)

State how the resistance of the diode can be determined from Fig. 6.1.

[1]



(b)

Four ideal diodes are arranged in the circuit as shown in Fig. 6.2.

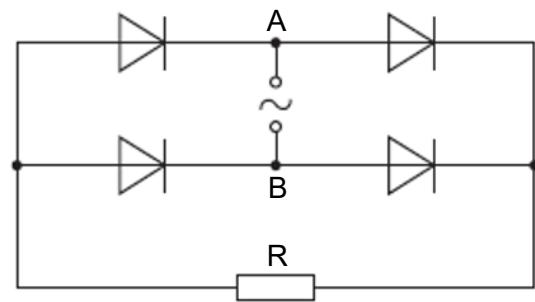


Fig. 6.2

A 7.0 V sinusoidal a.c. voltage supply at 25 Hz is applied between points A and B.

(i)

Circle the diode(s) that conduct when point B is positive with respect to point A. [1]

(ii)

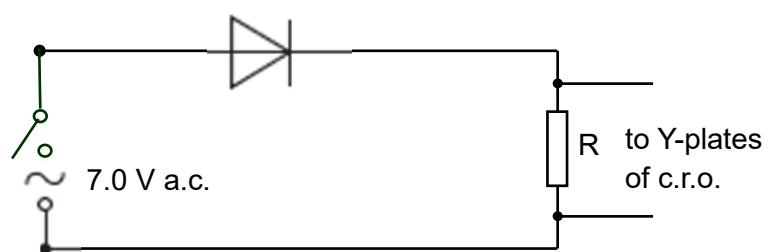
Calculate the maximum voltage  $V_{\max}$  across the resistor R.

$$V_{\max} = \dots \text{V} [1]$$



(iii)

Three of the diodes are removed and resistor R is connected to a diode, a cathode-ray oscilloscope (c.r.o.) and the 7.0 V sinusoidally-alternating voltage supply via a switch as shown in Fig. 6.3.



**Fig. 6.3**

The Y-plate sensitivity of the c.r.o is  $5.0 \text{ V cm}^{-1}$  and time base is  $10 \text{ ms cm}^{-1}$ .

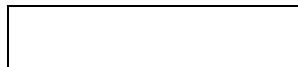
When the switch is opened, a horizontal trace is obtained as shown in Fig. 6.4.

**Fig. 6.4**



**1.**

Sketch, on Fig. 6.4, the full trace shown on the c.r.o. screen when the switch is closed.  
[2]



**2.**

Calculate the resistance of resistor R given that the mean power dissipated in it is 4.5 W.

$$\text{resistance} = \dots \Omega [2]$$

[Total: 10]